

MSB1218A-RT1G

PNP Silicon General Purpose Amplifier Transistor

This PNP Silicon Epitaxial Planar Transistor is designed for general purpose amplifier applications. This device is housed in the SC-70/SOT-323 package which is designed for low power surface mount applications.

Features

- High h_{FE} , 210 - 460
- Low $V_{CE(sat)}$, < 0.5 V
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

Rating	Symbol	Value	Unit
Collector-Base Voltage	$V_{(BR)CBO}$	45	Vdc
Collector-Emitter Voltage	$V_{(BR)CEO}$	45	Vdc
Emitter-Base Voltage	$V_{(BR)EBO}$	7.0	Vdc
Collector Current - Continuous	I_C	100	mAdc
Collector Current - Peak	$I_{C(P)}$	200	mAdc

THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Power Dissipation (Note 1)	P_D	150	mW
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min	Max	Unit
Collector-Emitter Breakdown Voltage ($I_C = 2.0$ mAdc, $I_B = 0$)	$V_{(BR)CEO}$	45	-	Vdc
Collector-Base Breakdown Voltage ($I_C = 10$ μ Adc, $I_E = 0$)	$V_{(BR)CBO}$	45	-	Vdc
Emitter-Base Breakdown Voltage ($I_E = 10$ μ Adc, $I_C = 0$)	$V_{(BR)EBO}$	7.0	-	Vdc
Collector-Base Cutoff Current ($V_{CB} = 20$ Vdc, $I_E = 0$)	I_{CBO}	-	0.1	μ A
Collector-Emitter Cutoff Current ($V_{CE} = 10$ Vdc, $I_B = 0$)	I_{CEO}	-	100	μ A
DC Current Gain (Note 2) ($V_{CE} = 10$ Vdc, $I_C = 2.0$ mAdc)	h_{FE1}	210	340	-
Collector-Emitter Saturation Voltage (Note 2) ($I_C = 100$ mAdc, $I_B = 10$ mAdc)	$V_{CE(sat)}$	-	0.5	Vdc

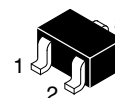
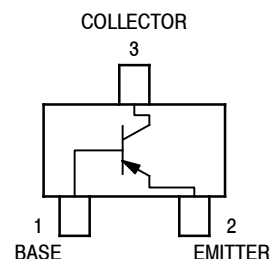
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint.
2. Pulse Test: Pulse Width ≤ 300 μ s, D.C. $\leq 2\%$.



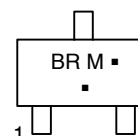
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SC-70 (SOT-323)
CASE 419
STYLE 4

MARKING DIAGRAM



BR = Device Code
M = Date Code*
▪ = Pb-Free Package

(Note: Microdot may be in either location)
*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping†
MSB1218A-RT1G	SC-70 (Pb-Free)	3000 /Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MSB1218A-RT1G

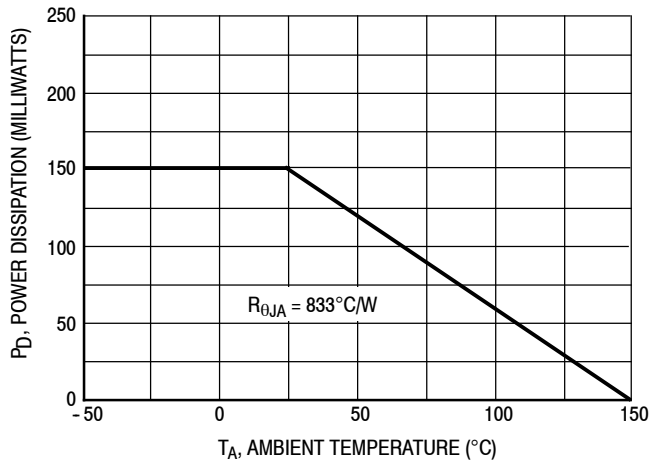


Figure 1. Derating Curve

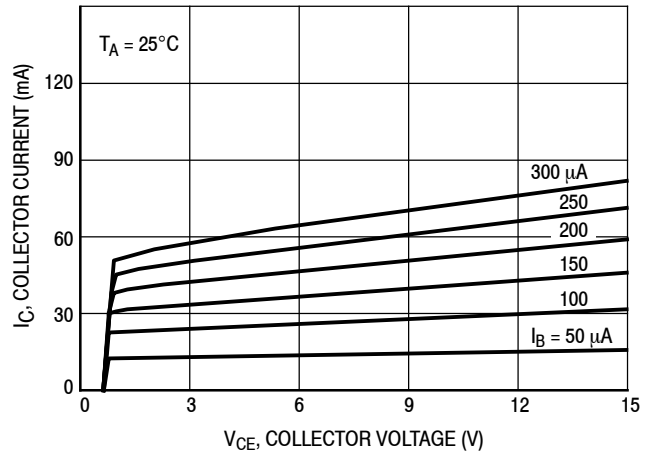


Figure 2. $I_C - V_{CE}$

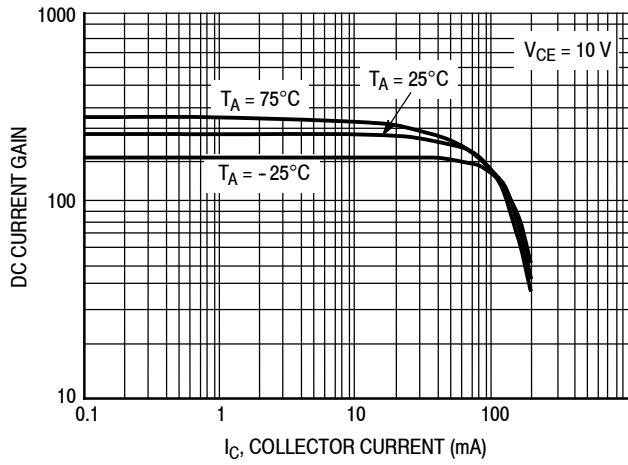


Figure 3. DC Current Gain

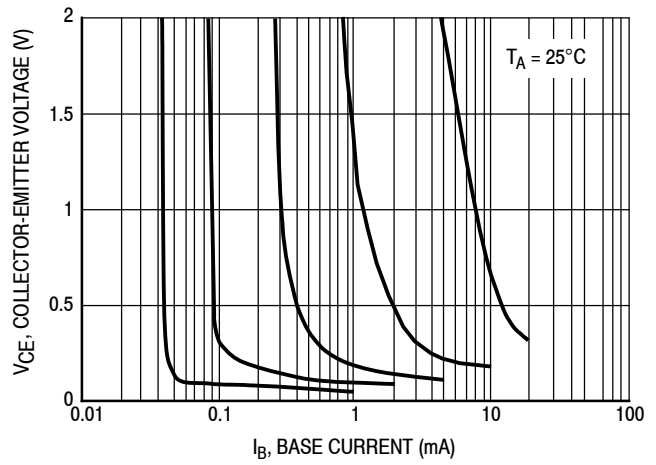


Figure 4. Collector Saturation Region

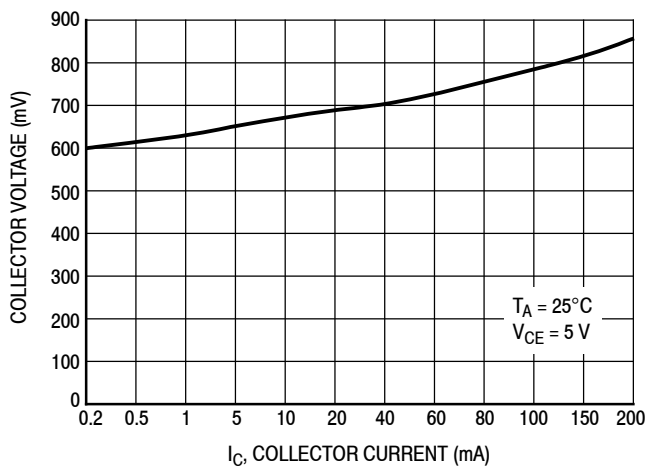


Figure 5. On Voltage

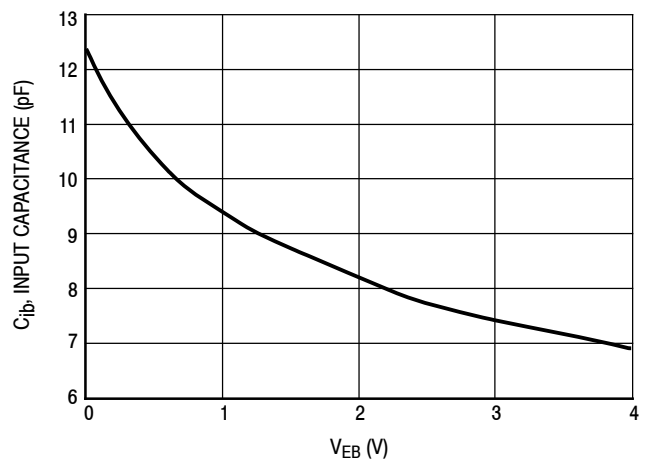


Figure 6. Capacitance

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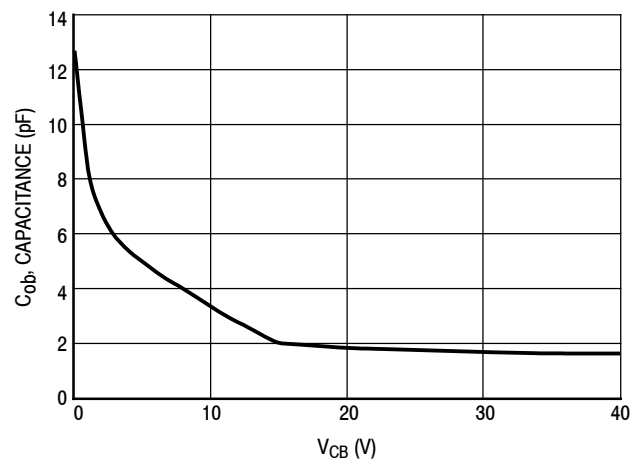


Figure 7. Capacitance

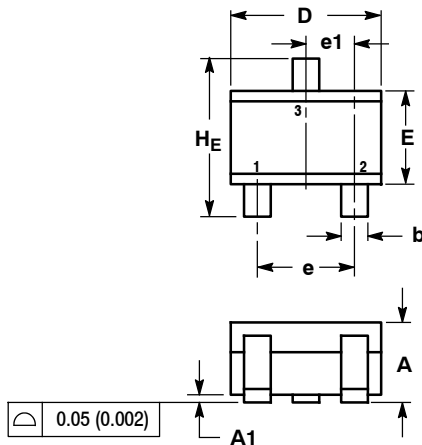
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PACKAGE DIMENSIONS

SC-70 (SOT-323)

CASE 419-04

ISSUE N



NOTES:

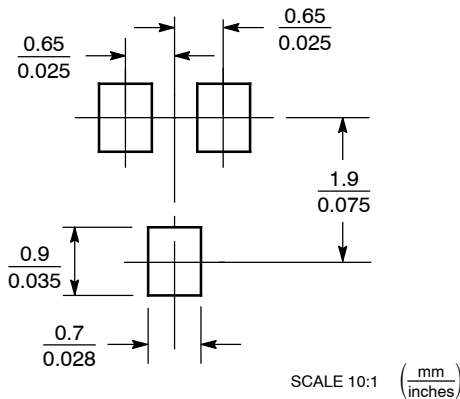
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.70 REF			0.028 REF		
b	0.30	0.35	0.40	0.012	0.014	0.016
c	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
e	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC			0.026 BSC		
L	0.20	0.38	0.56	0.008	0.015	0.022
HE	2.00	2.10	2.40	0.079	0.083	0.095

STYLE 4:

- PIN 1. CATHODE
- CATHODE
- ANODE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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MSB1218A-RT1/D

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Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

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